

# **DS1633** High-Speed Battery Recharger

DS1633

#### FEATURES

- · Recharges Lithium, NiCad, NiMH and Lead acid batteries
- Retains battery and power supply limits in onboard memory
- Serial 1-wire<sup>TM</sup> interface is used to program operating limits
- 3-pin TO-220 package
- Operating range 0°C to 70°C
- Applications include consumer electronics, portable/ ED cellular phones, pagers, medical instruments, backup memory systems, security systems
- Configurable to operate with 5V or 6V supplies

# . ov suppl.

#### **PIN ASSIGNMENT TO-220**



See Mech. Drawings Section

#### **PIN DESCRIPTION**

V <sub>CC</sub>	-	Supply Voltage
V <sub>BAT</sub>	-	Battery Output
GND	-	Ground

#### DESCRIPTION

The DS1633 Battery Recharger is designed to be a complete battery charging system for standard charge or trickle charge applications. It can be configured to be used with either 5V or 6V supplies and battery voltages as high as 4.7V (3.7V for 5V supplies). The device is flexible enough to be used with a variety of battery chemistries and cell capacities. It provides timer termination of standard charge and automatically shifts into trickle charge. Battery voltage can be monitored and charging terminated if it exceeds a preset maximum as a safety feature. The output load line can be specified as the usual constant current recharge with a voltage limit or it can be configured to approximate any practical load line. All parameters, such as power supply range, charge current load line, trickle charge rate, and timer setting, are programmed into nonvolatile memory using the battery pin as a 1-wire communication port. To ease the task of configuring the device to specific application needs, Dallas Semiconductor makes available a programming kit, the DS1633K, containing easy-to-use software and hardware for IBM personal computers.

The DS1633 is able to offer this flexibility due to its unique architecture (see Figure 1). The device monitors the battery voltage and adjusts the values of the output impedance ( $R_{TH}$ ) and open circuit voltage ( $V_{OC}$ ) it presents to the battery. These values can be adjusted at 32 user definable points (breakpoints) that occur roughly every 37 mV. This allows the device to approximate a wide range of charging lines; it is not limited to constant current or even monotonically decreasing functions.

### OPERATION

#### **Normal Mode**

Upon application of power, the DS1633 will perform an initialization cycle requiring eight seconds. During this period it will determine if a battery is connected to the battery input by applying a voltage through 5K $\Omega$  output impedance and looking for a non-zero current flow out of the pin. If a battery is connected, the value of the battery voltage will be determined using a 7-bit A/D convertor. This value will be used to determine which of the 32 user-defined breakpoints should be used to set R<sub>TH</sub> and  $V_{OC}$ . Generally, as the battery charges the battery voltage will increase. When the battery voltage reaches or exceeds each user-defined breakpoint, the values of R<sub>TH</sub> and V<sub>OC</sub> will be modified accordingly. The battery voltage is measured and adjustments are made every eight seconds. The battery detection is performed at one-second intervals. If the amount of time the battery has been charging exceeds the preset limit, the device will apply the VOC and RTH as before, but only for a fraction of the eight-second cycle time. This duty cycle can be as low as 1/64 or as high as 1. In this way trickle charge can be accomplished by time averaging a short pulse over a longer period. Refer to Figure 2 for a detailed flow diagram of normal operation.

#### **PROGRAMMING MODE**

#### **Register Structure**

To configure a DS1633 to operate with a unique load line the user must program a set of 25–bit internal registers (Table 1). The first 32 (0–31) of these registers contain the information needed to locate each breakpoint and what the  $R_{TH}$  and  $V_{OC}$  are at that breakpoint, as well as the duty cycle to be used after the optional timer has expired. The last (32) register contains the bits which

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select the system power supply level (5V or 6V), the timer option, and the time limit (2 to 32 hours in 2–hour increments).

## BREAKPOINT REGISTER STRUCTURE Break Point Voltage Field

The break point voltage field specifies the range of battery voltage over which the  $R_{TH}$ ,  $V_{OC}$  and pulse frequency information contained in that register is valid. This information is valid when the battery voltage meets or exceeds the breakpoint value, but is less than the next breakpoint value:

$$V_{BPX} \le V_{BAT} < V_{BP(x+1)}$$

The xth breakpoint voltage ( $V_{\text{BPX}}$ ) is determined according to the following formula:

$$V_{BPX}(n) = (n/127)(4.699V)$$
; for  $0 \le n \le 127$ 

The value for n is entered in the field as a 7-bit binary value, LSB first. For reliable operation the first (x=0) breakpoint should be programmed such that  $V_{BP0} = 0$ . Successive breakpoints should be programmed with increasing values, that is:

#### $V_{BPX} < V_{BP(x+1)}$

If not all of the available breakpoints are used, the unused points should be assigned the maximum V<sub>BP</sub> value (n=127) of 4.699V with R<sub>TH</sub> and V<sub>OC</sub> set to their maximum values (5060 $\Omega$  and 5.5V) and the duty cycle field set to its minimum or zero value.

#### **OPEN CIRCUIT VOLTAGE FIELD**

The open circuit voltage field specifies the value of V<sub>OC</sub> to be applied to the battery. V<sub>OC</sub> can be set for values between 1.3V and 5.5V. This field is entered as a 7–bit binary value, LSB first. The value of V<sub>OC</sub>(n) is determined as follows:

 $V_{OC}(n) = 1.3V + n(5.5V - 1.3V)/127$ ; for  $0 \le n \le 127$ 

For reliable operation of the battery detection circuitry, the minimum value of  $V_{OC}$  should be greater than the maximum battery voltage.

#### THEVENIN RESISTANCE FIELD

The Thevenin resistance field specifies the value of output resistance between the low impedance V<sub>OC</sub> source and the battery pin. This resistance can have one of 128 values ranging from  $5060\Omega$  to  $7.5\Omega$  with a 5% difference in successive values. This field is entered as a 7–bit binary value, LSB first. The value of R<sub>TH</sub>(n) is determined as follows:

$$R_{TH}(n) = 7.5(0.95^{n-127})$$
; for  $0 \le n \le 127$ 

#### PULSE WIDTH FIELD

The pulse width field specifies the amount of time (PW) during each eight second charging and evaluation cycle that  $V_{OC}$  and  $R_{TH}$  will be applied after the optional timer has expired. PW can have one of 8 values ranging from 8 seconds to 0. The field is entered as a 3-bit binary value, LSB first. The value of PW is determined as follows:

$$PW(n) = 2^{n}/16$$
; for  $1 \le n \le 7$ 

$$PW(n) = 0$$
; for  $n = 0$ 

#### **CHARGE ON FIELD**

This is a one bit field which specifies if  $V_{OC}$  and  $R_{TH}$  for this breakpoint are to be applied at all for the case of an unexpired timer. Its usefulness is in permitting certain breakpoints to be turned off if the battery voltage exceeds a maximum during standard charge. If the timer has expired or is not used, this is accomplished for those breakpoints using the 3 pulse width bits (PW = 000).

A one in this field means that the  $V_{\mbox{\scriptsize OC}}$  and  $R_{\mbox{\scriptsize TH}}$  are to be applied when the breakpoint is the current one.

#### **CONFIGURATION REGISTER STRUCTURE**

#### V<sub>TRIP</sub> Field

This is a one-bit field which specifies the valid supply voltage for the device. A one in this field indicates a 6V system is being used and the part will not begin charging until the applied  $V_{CC}$  exceeds 5.7V. Conversely, a zero

indicates a 5V system and charging will begin when  $V_{CC}$  exceeds 4.75V.

#### TIMER STATUS FIELD

This is a one bit field which indicates if the timer is to be used. A one in this field indicates that timer is used, a zero that it is not.

#### TIMER VALUE FIELD

This field specifies the maximum time (T<sub>MAX</sub>) for standard or non–pulsed charging. During the period when the timer has not expired, V<sub>OC</sub> and R<sub>TH</sub> will be applied to the battery input if the charge on bit is a one. When the elapsed charge time exceeds the value in this register, V<sub>OC</sub> and R<sub>TH</sub> will be applied at a duty cycle determined by the PW field for each breakpoint. The field is entered as a 4–bit binary value, LSB first. The timer can have values from 2 to 32 hours, determined by the following:

$$T_{MAX}(n) = 2(n + 1)$$
; for  $0 \le n \le 15$ 

# PROGRAMMING OPERATION

The data for the 33 registers is stored in nonvolatile memory and can be written only once. All 33 registers must be programmed before any can be read. Note that although the configuration register contains only 6 bits, 25 bits are required to be entered; therefore, fill it with 19 0's. The registers are programmed sequentially, starting at register 0. As each register is programmed, an internal pointer moves to the next register until all 33 have been programmed. To enter the program/read mode,  $V_{CC}$  must be taken to 8V for a minimum of 1 ms and returned to 5V. The V<sub>BAT</sub> pin is now configured to operate as a single wire I/O line. The hardware interface is shown in Figure 3.

#### **RESET TIMING**

To issue a reset to the device the  $V_{BAT}$  pin must be brought low and held low for a minimum of 480 µs after which it is released and will return to a high level through the internal pullup resistor. After the line is allowed to return high it must not be pulled low for at least 1 µs. Refer to Figure 4. A logic 0 is written by bringing the V<sub>BAT</sub> pin low for at least 60 µs, but not more than 120 µs. A logic 1 is written by bringing the  $V_{\text{BAT}}$  pin low for at least 1  $\mu s,$  but not more than 15 µs. After the line is allowed to return high it must not be pulled low for at least 60 µs. Refer to Figure 4.

#### **READ TIMING**

A read is performed by bringing the  $V_{\text{BAT}}$  pin low for at least 1  $\mu s$ , but not more than 5  $\mu s$  and then releasing it. A logic 1 is indicated by the pin returning high. The state of the V<sub>BAT</sub> pin should be sampled at most 15  $\mu$ s after V<sub>BAT</sub> is pulled low. A high level indicates a read '1', a low level indicates a read '0'.

#### PROGRAMMING

To program the DS1633 the single line I/O must be enabled by bringing  $V_{CC}$  to 8V for at least 1 ms and then back to 5V. The first register can now be written. The register data must be preceded by 3 consecutive logic 1 write cycles. The register data can now be entered

according to the write cycle timing detailed above, from LSB to MSB. To commit the data to the nonvolatile memory the V<sub>BAT</sub> pin is brought to 12V, with V<sub>CC</sub> at 8V, for at least 250 ms. When  $\mathsf{V}_{\mathsf{BAT}}$  is released and returns to 5V and a reset cycle is issued the device is ready for the next register. Be careful not to issue multiple resets as this will move the pointer. This sequence is repeated until all 33 registers are programmed. When all registers have been programmed, the DS1633 disables the serial interface and begins normal operation.

#### VERIFICATION

To verify the data contained in the registers the single line I/O must be enabled by bringing  $V_{CC}$  to 8V for at least 1 ms. Unlike the programming operation, the read operation allows random access of the registers. A read cycle is preceded by 4 logic ones, a 6-bit register address, entered LSB first, and 18 logic ones. The device will now output the contents of the register, LSB first, on the next 25 read cycles. To read another register, issue a reset and repeat the sequence.



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## SIMPLIFIED BLOCK DIAGRAM Figure 1



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# DS1633 OPERATION FLOW CHART Figure 2

![](_page_5_Figure_2.jpeg)

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![](_page_6_Figure_1.jpeg)

HARDWARE INTERFACE FOR PROGRAMMING Figure 3

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# REGISTER VALUE CROSS REFERENCE Table 2

HEX	DEC	R <sub>TH</sub>	Voc	V <sub>BP</sub>	
00	0	5.060E+03	1.30	0.000	
01	1	4.807E+03	1.33	0.037	
02	2	4.567E+03	1.37	0.074	
03	3	4.338E+03	1.40	0.111	
04	4	4.122E+03	1.43	0.148	
05	5	3.915E+03	1.47	0.185	
06	6	3.720E+03	1.50	0.222	
07	7	3.534E+03	1.53	0.259	
08	8	3.357E+03	1.56	0.296	[
09	9	3.189E+03	1.60	0.333	Í
0A	10	3.030E+03	1.63	0.370	í ľ
0B	11	2.878E+03	1.66	0.407	í ľ
0C	12	2.734E+03	1.70	0.444	Í ľ
0D	13	2.598E+03	1.73	0.481	Í
0E	14	2.468E+03	1.76	0.518	Í ľ
0F	15	2.344E+03	1.80	0.555	
10	16	2.227E+03	1.83	0.592	
11	17	2.116E+03	1.86	0.629	í [
12	18	2.010E+03	1.90	0.666	
13	19	1.909E+03	1.93	0.703	
14	20	1.814E+03	1.96	0.740	
15	21	1.723E+03	1.99	0.777	
16	22	1.637E+03	2.03	0.814	ĺ
17	23	1.555E+03	2.06	0.851	i L
18	24	1.478E+03	2.09	0.888	i L
19	25	1.404E+03	2.13	0.925	i L
1A	26	1.333E+03	2.16	0.962	i L
1B	27	1.267E+03	2.19	0.999	i L
1C	28	1.203E+03	2.23	1.036	i L
1D	29	1.143E+03	2.26	1.073	ĺ
1E	30	1.086E+03	2.29	1.110	
1F	31	1.032E+03	2.33	1.147	
20	32	9.802E+02	2.36	1.184	
21	33	9.312E+02	2.39	1.221	[
22	34	8.846E+02	2.42	1.258	[
23	35	8.404E+02	2.46	1.295	[
24	36	7.984E+02	2.49	1.332	ļ
25	37	7.585E+02	2.52	1.369	[

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	HEX	DEC	R <sub>TH</sub>	V <sub>oc</sub>	V <sub>BP</sub>
	26	38	7.205E+02	2.56	1.406
	27	39	6.845E+02	2.59	1.443
	28	40	6.503E+02	2.62	1.480
	29	41	6.178E+02	2.66	1.517
	2A	42	5.869E+02	2.69	1.554
	2B	43	5.575E+02	2.72	1.591
	2C	44	5.297E+02	2.76	1.628
	2D	45	5.032E+02	2.79	1.665
	2E	46	4.780E+02	2.82	1.702
	2F	47	4.541E+02	2.85	1.739
	30	48	4.314E+02	2.89	1.776
	31	49	4.098E+02	2.92	1.813
	32	50	3.894E+02	2.95	1.850
	33	51	3.699E+02	2.99	1.887
	34	52	3.514E+02	3.02	1.924
	35	53	3.338E+02	3.05	1.961
	36	54	3.171E+02	3.09	1.998
	37	55	3.013E+02	3.12	2.035
	38	56	2.862E+02	2.15	2.072
	39	57	2.719E+02	3.19	2.109
	3A	58	2.583E+02	3.22	2.146
	3B	59	2.454E+02	3.25	2.183
	3C	60	2.331E+02	3.28	2.220
	3D	61	2.215E+02	3.32	2.257
	3E	62	2.104E+02	3.35	2.294
	3F	63	1.999E+02	3.38	2.331
	40	64	1.899E+02	3.42	2.368
	41	65	1.804E+02	3.45	2.405
	42	66	1.714E+02	3.48	2.442
	43	67	1.628E+02	3.52	2.479
	44	68	1.547E+02	3.55	2.516
	45	69	1.469E+02	3.58	2.553
	46	70	1.396E+02	3.61	2.590
	47	71	1.326E+02	3.65	2.627
	48	72	1.260E+02	3.68	2.664
	49	73	1.197E+02	3.71	2.701
	4A	74	1.137E+02	3.75	2.738
	4B	75	1.080E+02	3.78	2.775

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HEX	DEC	R <sub>TH</sub>	V <sub>oc</sub>	V <sub>BP</sub>	
4C	76	1.026E+02	3.81	2.812	
4D	77	9.747E+01	3.85	2.849	
4E	78	9.260E+01	3.88	2.886	
4F	79	8.797E+01	3.91	2.923	
50	80	8.357E+01	3.95	2.960	
51	81	7.939E+01	3.98	2.997	
52	82	7.542E+01	4.01	3.034	
53	83	7.165E+01	4.04	3.071	
54	84	6.807E+01	4.08	3.108	
55	85	6.467E+01	4.11	3.145	
56	86	6.143E+01	4.14	3.182	
57	87	5.836E+01	4.18	3.219	
58	88	5.544E+01	4.21	3.256	
59	89	5.267E+01	4.24	3.293	
5A	90	5.004E+01	4.28	3.330	
5B	91	4.753E+01	4.31	3.367	
5C	92	4.516E+01	4.34	3.404	
5D	93	4.290E+01	4.38	3.441	
5E	94	4.076E+01	4.41	3.478	
5F	95	3.873E+01	4.44	3.515	
60	96	3.678E+01	4.47	3.552	
61	97	3.494E+01	4.51	3.589	
62	98	3.320E+01	4.54	3.626	
63	99	3.154E+01	4.57	3.663	
64	100	2.996E+01	4.61	3.700	
65	101	2.846E+01	4.64	3.737	

HEX	DEC	R <sub>TH</sub>	V <sub>oc</sub>	V <sub>BP</sub>
66	102	2.704E+01	4.67	3.774
67	103	2.569E+01	4.71	3.811
68	104	2.440E+01	4.74	3.848
69	105	2.318E+01	4.77	3.885
6A	106	2.202E+01	4.81	3.922
6B	107	2.092E+01	4.84	3.959
6C	108	1.988E+01	4.87	3.996
6D	109	1.888E+01	4.90	4.033
6E	110	1.794E+01	4.94	4.070
6F	111	1.704E+01	4.97	4.107
70	112	1.619E+01	5.00	4.144
71	113	1.538E+01	5.04	4.181
72	114	1.461E+01	5.07	4.218
73	115	1.388E+01	5.10	4.255
74	116	1.319E+01	5.14	4.292
75	117	1.253E+01	5.17	4.329
76	118	1.190E+01	5.20	4.366
77	119	1.131E+01	5.24	4.403
78	120	1.074E+01	5.27	4.440
79	121	1.020E+01	5.30	4.477
7A	122	9.693E+00	5.33	4.514
7B	123	9.208E+00	5.37	4.551
7C	124	8.748E+00	5.40	4.588
7D	125	8.310E+00	5.43	4.625
7E	126	7.895E+00	5.47	4.662
7F	127	7.500E+00	5.50	4.699

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ABSOLUTE MAXIMUM RATINGS\* Voltage on Any Pin Relative to Ground Operating Temperature Storage Temperature Soldering Temperature

-1.0V to +7.0V 0°C to 70°C -55°C to +125°C 260°C for 10 seconds

\* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED DC OPERATING CONDITIONS (0°C to 70°							
PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES	
5V Mode Supply Voltage, Operation	V <sub>CC1</sub>	4.75	5	6.5	V	1, 2	
6V Mode Supply Voltage, Operation	V <sub>CC2</sub>	5.7	6	6.5	V	1, 3, 4	
Supply Voltage, V <sub>BAT</sub> , Programming	V <sub>BATP</sub>	12	12	13	V		
I <sub>BAT</sub> , Programming	I <sub>BATP</sub>			100	μA		
V <sub>CC</sub> Supply Voltage, Programming	V <sub>CC3</sub>	8	R	8.5	V		
Logic 1 Input	V <sub>IH</sub>	2.0	-	V <sub>CC</sub> +0.3	V		
Logic 0 Input	V <sub>IL</sub>	-0.3	_	+0.8	V		

۲L	0.0		10.0	v				
DC ELECTRICAL CHARACTERISTICS (0°C to 70°C: V <sub>CC</sub> =5.75V								
SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES			
I <sub>CC1,2</sub>			1	mA	6			
I <sub>CC3</sub>			10	mA				
V <sub>OL</sub>			0.4	V				
I <sub>OL</sub>	1			mA				
I <sub>BAT</sub>			100	nA	5			
R <sub>PU</sub>		5K						
V <sub>BP</sub> (0)		0		V				
V <sub>BP</sub> (127)	4.649	4.699	4.749	V				
V <sub>OC</sub> (0)		1.3		V				
V <sub>OC</sub> (127)	5.45	5.50	5.55	V				
R <sub>TH</sub> (0)		7.5		Ω	7			
R <sub>TH</sub> (127)	4933	5060	5187	Ω	7			
T <sub>MAX</sub> (0)	1.8	2	2.2	hours				
T <sub>MAX</sub> (127)	28.8	32	35.2	hours				
	VIL           SYMBOL           Icc1,2           Icc3           VoL           IoL           BAT           RPU           VBP(0)           VBP(0)           VOC(0)           VOC(127)           RTH(0)           RTH(127)           TMAX(0)           TMAX(127)	VIL         0.0           SYMBOL         MIN           I <sub>CC1,2</sub>	NIL         O.S           SYMBOL         MIN         TYP           I <sub>CC1,2</sub>	NIL         O.0         NO           RISTICS         (0°C           SYMBOL         MIN         TYP         MAX $I_{CC1,2}$ 1         1         1 $I_{CC3}$ 10         0.4         10 $V_{OL}$ 0.4         10         0.4 $I_{OL}$ 1         100         10 $R_{PU}$ 5K         100         0 $R_{PU}$ 5K         100         0 $V_{BP}(0)$ 0         0         0 $V_{BP}(127)$ 4.649         4.699         4.749 $V_{OC}(0)$ 1.3         100         0 $V_{OC}(127)$ 5.45         5.50         5.55 $R_{TH}(0)$ 7.5         5.87         5.87 $R_{TH}(127)$ 4933         5060         5187 $T_{MAX}(0)$ 1.8         2         2.2 $T_{MAX}(127)$ 28.8         32         35.2	NIL         O.O         NO.O         V           RISTICS         (0°C to 70°C; V         MAX         UNITS $I_{CC1,2}$ 1         mA         UNITS $I_{CC3}$ 10         mA         UNITS $I_{CC3}$ 10         mA         V $I_{OL}$ 0.4         V         V $I_{OL}$ 1         mA         MAX $I_{BAT}$ 100         nA         V $V_{BP}(0)$ 0         V         V $V_{BP}(127)$ 4.649         4.699         4.749         V $V_{OC}(0)$ 1.3         V         V         V $V_{OC}(127)$ 5.45         5.50         5.55         V $R_{TH}(0)$ 7.5 $\Omega$ $\Omega$ $\Omega$ $T_{MAX}(0)$ 1.8         2         2.2         hours $T_{MAX}(127)$ 28.8         32         35.2         hours			

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# AC ELECTRICAL CHARACTERISTICS: DATA TRANSMISSION PARAMETERS

PARAMETER	SYMBOL	MIN	ТҮР	MAX	UNITS	NOTES	
Reset Active	t <sub>R</sub>	480			μs		
Logic 1 Active Low	t <sub>1</sub>	1		15	μs		
Logic 0 Active Low	t <sub>0</sub>	60		120	μs		
Read Enable Time	t <sub>READ</sub>	1		5	μs		
Time from Read Enable to I/O Line Sampling	t <sub>SAMPLE</sub>			15	μs		
Data Transfer Window	t <sub>TS</sub>	60		120	μs		
Active Signal Pulse Width, Data I/O	t <sub>PW</sub>	60		120	μs	GN	
Recovery Time Between Windows	t <sub>REC</sub>	1			μs		
Programming Pulse Width, V <sub>BAT</sub>	t <sub>PRG</sub>	250			ms		
NOTES: 1. All voltages referenced to ground. 2. 5V operation conditions. 3. 6V operation conditions.							
4. For any $V_{OCMAX} \ge 4.5V$ , $V_{TRIP} = 5.7V$ (6V operation) must be used.							

# NOTES:

- 1. All voltages referenced to ground.
- 2. 5V operation conditions.
- 3. 6V operation conditions.
- 4. For any  $V_{OCMAX} \geq$  4.5V,  $V_{TRIP}$  = 5.7V (6V operation) must be used.
- 5. High impedance isolation between V\_BAT and V\_CC with V\_CC=0 is  $\geq 45 G \Omega.$
- 6. Does not include current supplied to the battery pin.
- 7. At 25°C, R<sub>TH</sub> has a positive temperature coefficient of approximately 800 ppm/°C.

#### DATA SHEET REVISION SUMMARY

The following represent the key differences between 05/26/94 and 11/08/97 version of the DS1633 data sheet. Please review this summary carefully.

1. STATUS CHANGE: "NOT RECOMMENDED FOR NEW DESIGN"

NOT RECOMMENDED FOR NEW DESIGN

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DS1633